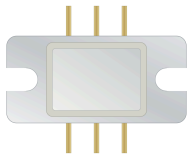
1200–1600 MHz GaN Packaged Power Amplifier — PSAT ≥ 42 dBm

LCI-PA-1200-1600-PS42MIN · 1200–1600 MHz · GaN Packaged Power Amplifier.

The RF table specifies: PSAT ≥ 42 dBm; Power gain ≥ 16 dB; PAE 55 % (typical). RF test conditions: Vd = +28 V; Vg = -1.8; D = 10%; Pin = 26 dBm.



CMW010B

Apply gate bias before drain bias. Remove drain bias before gate bias.

Vg: C = 10 µF

Vg: 1, 3

RFin: 2

Vd: 4, 6

RFout: 5

Package outline dimensions: 18.03 × 8.7 mm.

RF characteristics

Vd = +28 V; Vg = -1.8; D = 10%; Pin = 26 dBm

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Operating frequency	f	1200	-	1600	MHz
Saturated output power	-	42	-	-	dBm
Power gain	-	16	-	-	dB
Power-added efficiency	-	45	55	-	%
Power-gain flatness	-	-	-	1	dB

DC bias and current

Parameter	Symbol	Minimum	Typical	Maximum	Value	Unit
Drain voltage	-	-	-	-	28	V
Gate voltage	-	-	-	-	-1.8	V

Absolute limits

Absolute limits; these are not normal operating targets.

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Maximum drain-source voltage	-	-	-	32	V
Minimum gate bias	-	-5	-	-	V
Storage temperature	-	-65	-	150	°C
Maximum input power	-	-	-	30	dBm

Absolute limits

Absolute limits; these are not normal operating targets.

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Maximum channel temperature	-	-	-	225	°C

Package outline dimensions

Parameter	Value	Unit
Package outline dimensions	18.03 × 8.7	mm
Terminal span	14.7	mm

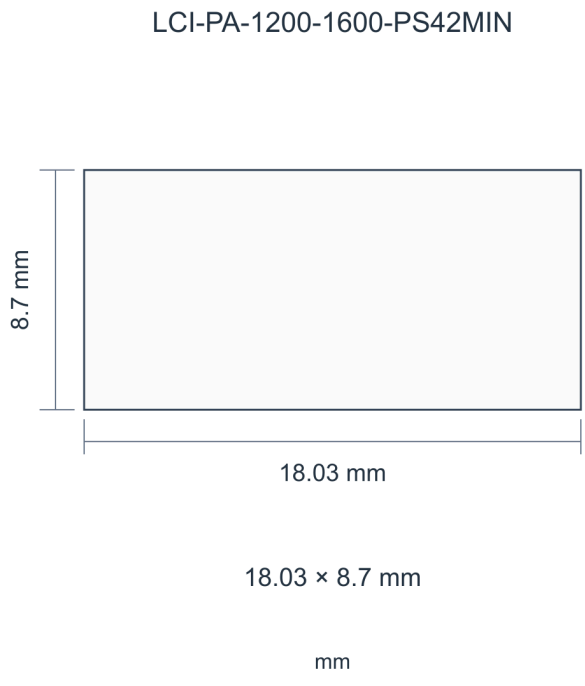
Current publication record · 1.6 · 2026-11-12. Product description or editorial content updated. Replaces revision 1.5.

Integration notes

CMW010B Apply gate bias before drain bias. Remove drain bias before gate bias. Vg: C = 10 µF Vg: 1, 3 RFin: 2 Vd: 4, 6 RFout: 5

Mechanical Outline

Partial drawing showing confirmed dimensions in mm. Use the complete installation drawing for installation.

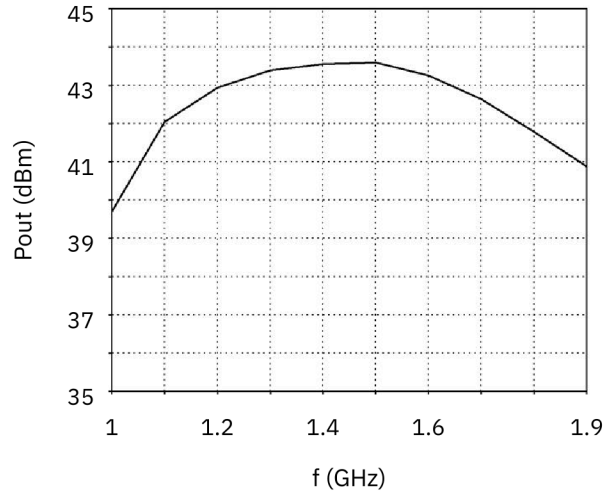


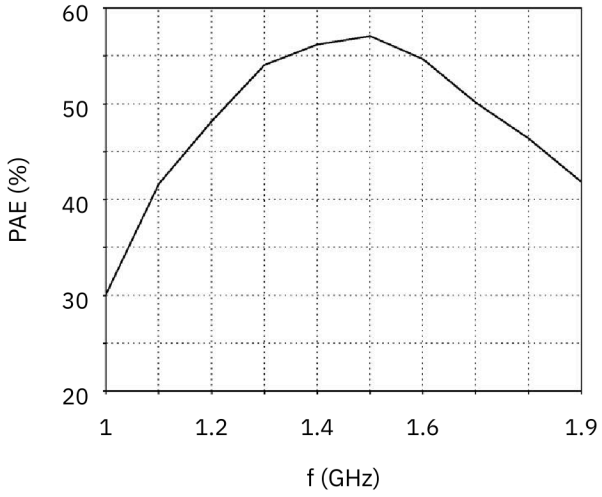
Performance curves

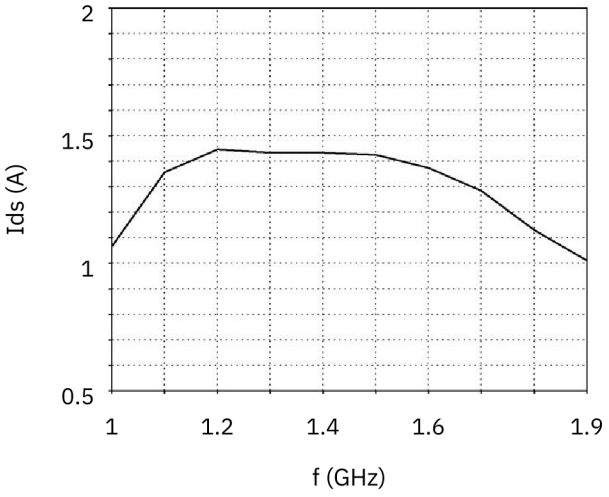
Each performance plot applies to its stated operating conditions.

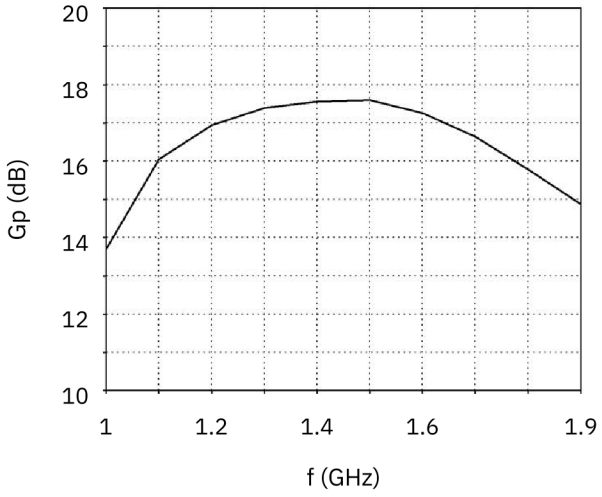
Saturated output power; Power-added efficiency; Dynamic drain current; Power gain.

Figure notes: TA=+25°C; Vd=+28V; Vg=-1.8V; Pin=26dBm. D = 10%.



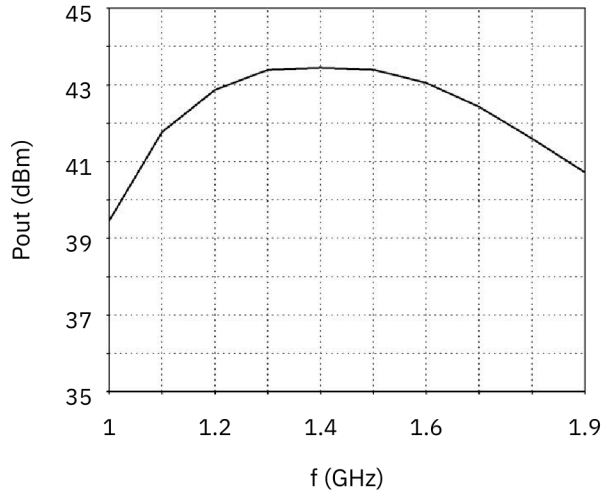


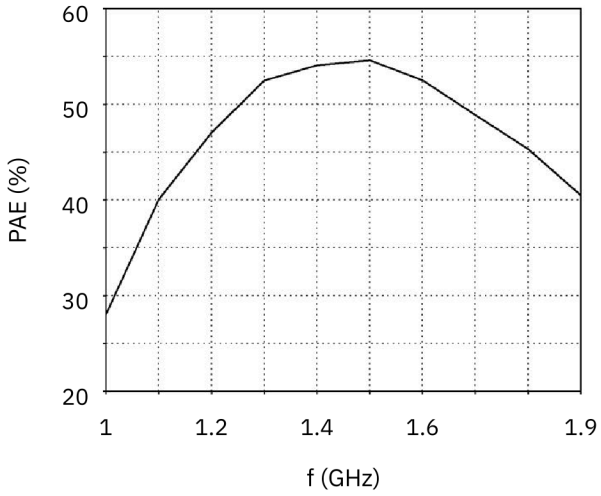


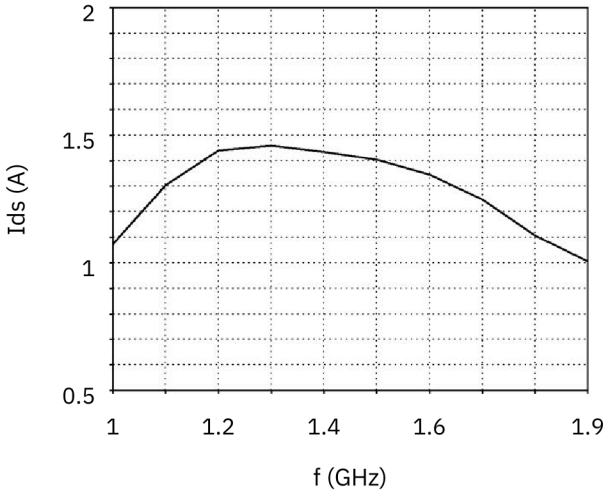


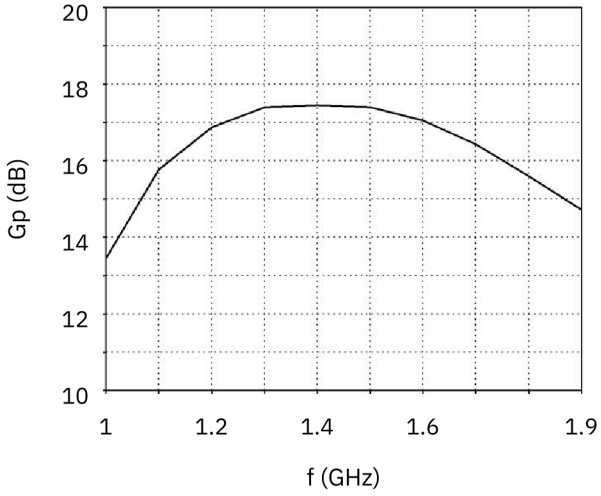
Continuous wave (CW) — Saturated output power; Power-added efficiency; Dynamic drain current; Power gain.

Figure notes: TA=+25°C; Vd=+28V; Vg=-1.8V; Pin=26dBm.









Document notice

Specifications are subject to revision. Before design release, confirm the current document revision and product-specific requirements with LCRF. The approved quotation and order documentation define the supplied configuration.